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Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

| Details | |
|--------------------------------|--|
| Product Status | Obsolete |
| Number of LABs/CLBs | 185000 |
| Number of Logic Elements/Cells | 490000 |
| Total RAM Bits | 46080000 |
| Number of I/O | 600 |
| Number of Gates | - |
| Voltage - Supply | 0.87V ~ 0.93V |
| Mounting Type | Surface Mount |
| Operating Temperature | 0°C ~ 85°C (TJ) |
| Package / Case | 1517-BBGA, FCBGA |
| Supplier Device Package | 1517-FBGA (40x40) |
| Purchase URL | https://www.e-xfl.com/product-detail/intel/5sgxea5n1f40c2n |

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Page 2 Electrical Characteristics

Table 1. Stratix V GX and GS Commercial and Industrial Speed Grade Offering (1), (2), (3) (Part 2 of 2)

| Transceiver Speed | Core Speed Grade | | | | | | | | | | | |
|-----------------------|------------------|---------|-----|-----|---------|---------|--------------------|-----|--|--|--|--|
| Grade | C1 | C2, C2L | C3 | C4 | 12, 12L | 13, 13L | I3YY | 14 | | | | |
| 3 GX channel—8.5 Gbps | _ | Yes | Yes | Yes | _ | Yes | Yes ⁽⁴⁾ | Yes | | | | |

Notes to Table 1:

- (1) C = Commercial temperature grade; I = Industrial temperature grade.
- (2) Lower number refers to faster speed grade.
- (3) C2L, I2L, and I3L speed grades are for low-power devices.
- (4) I3YY speed grades can achieve up to 10.3125 Gbps.

Table 2 lists the industrial and commercial speed grades for the Stratix V GT devices.

Table 2. Stratix V GT Commercial and Industrial Speed Grade Offering (1), (2)

| Transacius Snood Crada | Core Speed Grade | | | | | | | | | |
|--|------------------|-----|-----|-----|--|--|--|--|--|--|
| Transceiver Speed Grade | C1 | C2 | 12 | 13 | | | | | | |
| 2 GX channel—12.5 Gbps GT channel—28.05 Gbps | Yes | Yes | _ | _ | | | | | | |
| 3 GX channel—12.5 Gbps GT channel—25.78 Gbps | Yes | Yes | Yes | Yes | | | | | | |

Notes to Table 2:

- (1) C = Commercial temperature grade; I = Industrial temperature grade.
- (2) Lower number refers to faster speed grade.

Absolute Maximum Ratings

Absolute maximum ratings define the maximum operating conditions for Stratix V devices. The values are based on experiments conducted with the devices and theoretical modeling of breakdown and damage mechanisms. The functional operation of the device is not implied for these conditions.



Conditions other than those listed in Table 3 may cause permanent damage to the device. Additionally, device operation at the absolute maximum ratings for extended periods of time may have adverse effects on the device.

Table 3. Absolute Maximum Ratings for Stratix V Devices (Part 1 of 2)

| Symbol | Description | Minimum | Maximum | Unit |
|---------------------|--|---------|---------|------|
| V _{CC} | Power supply for core voltage and periphery circuitry | -0.5 | 1.35 | V |
| V _{CCPT} | Power supply for programmable power technology | -0.5 | 1.8 | V |
| V _{CCPGM} | Power supply for configuration pins | -0.5 | 3.9 | V |
| V _{CC_AUX} | Auxiliary supply for the programmable power technology | -0.5 | 3.4 | V |
| V _{CCBAT} | Battery back-up power supply for design security volatile key register | -0.5 | 3.9 | V |
| V _{CCPD} | I/O pre-driver power supply | -0.5 | 3.9 | V |
| V _{CCIO} | I/O power supply | -0.5 | 3.9 | V |

Electrical Characteristics Page 5

Recommended Operating Conditions

This section lists the functional operating limits for the AC and DC parameters for Stratix V devices. Table 6 lists the steady-state voltage and current values expected from Stratix V devices. Power supply ramps must all be strictly monotonic, without plateaus.

Table 6. Recommended Operating Conditions for Stratix V Devices (Part 1 of 2)

| Symbol | Description | Condition | Min ⁽⁴⁾ | Тур | Max ⁽⁴⁾ | Unit |
|----------------------------------|--|------------|--------------------|------|--------------------|------|
| | Core voltage and periphery circuitry power supply (C1, C2, I2, and I3YY speed grades) | _ | 0.87 | 0.9 | 0.93 | V |
| V _{CC} | Core voltage and periphery circuitry power supply (C2L, C3, C4, I2L, I3, I3L, and I4 speed grades) (3) | _ | 0.82 | 0.85 | 0.88 | V |
| V _{CCPT} | Power supply for programmable power technology | _ | 1.45 | 1.50 | 1.55 | V |
| V _{CC_AUX} | Auxiliary supply for the programmable power technology | _ | 2.375 | 2.5 | 2.625 | V |
| V (1) | I/O pre-driver (3.0 V) power supply | | 2.85 | 3.0 | 3.15 | V |
| V _{CCPD} ⁽¹⁾ | I/O pre-driver (2.5 V) power supply | | 2.375 | 2.5 | 2.625 | V |
| | I/O buffers (3.0 V) power supply | _ | 2.85 | 3.0 | 3.15 | ٧ |
| | I/O buffers (2.5 V) power supply | _ | 2.375 | 2.5 | 2.625 | V |
| | I/O buffers (1.8 V) power supply | _ | 1.71 | 1.8 | 1.89 | ٧ |
| V_{CCIO} | I/O buffers (1.5 V) power supply | _ | 1.425 | 1.5 | 1.575 | V |
| | I/O buffers (1.35 V) power supply | | 1.283 | 1.35 | 1.45 | V |
| | I/O buffers (1.25 V) power supply | | 1.19 | 1.25 | 1.31 | V |
| | I/O buffers (1.2 V) power supply | _ | 1.14 | 1.2 | 1.26 | V |
| | Configuration pins (3.0 V) power supply | | 2.85 | 3.0 | 3.15 | V |
| V_{CCPGM} | Configuration pins (2.5 V) power supply | _ | 2.375 | 2.5 | 2.625 | V |
| | Configuration pins (1.8 V) power supply | _ | 1.71 | 1.8 | 1.89 | V |
| V _{CCA_FPLL} | PLL analog voltage regulator power supply | | 2.375 | 2.5 | 2.625 | V |
| V _{CCD_FPLL} | PLL digital voltage regulator power supply | | 1.45 | 1.5 | 1.55 | V |
| V _{CCBAT} (2) | Battery back-up power supply (For design security volatile key register) | _ | 1.2 | _ | 3.0 | V |
| V _I | DC input voltage | _ | -0.5 | _ | 3.6 | V |
| V ₀ | Output voltage | _ | 0 | _ | V _{CCIO} | V |
| т. | Operating junction temperature | Commercial | 0 | _ | 85 | °C |
| T _J | Operating junction temperature | Industrial | -40 | _ | 100 | °C |

Electrical Characteristics Page 15

Table 19. Single-Ended SSTL, HSTL, and HSUL I/O Standards Signal Specifications for Stratix V Devices (Part 2 of 2)

| I/O Standard | V _{IL(D(} | ; ₎ (V) | V _{IH(D} | _{C)} (V) | V _{IL(AC)} (V) | V _{IH(AC)} (V) | V _{OL} (V) | V _{OH} (V) | I _{ol} (mA) | l _{oh} |
|---------------------|--------------------|---------------------------|-------------------------|--------------------------|----------------------------|-------------------------|----------------------------|----------------------------|------------------------|-----------------|
| i/O Stanuaru | Min | Max | Min | Max | Max | Min | Max | Min | I _{OI} (IIIA) | (mA) |
| HSTL-18 Class I | _ | V _{REF} – 0.1 | V _{REF} + 0.1 | _ | V _{REF} - 0.2 | V _{REF} + 0.2 | 0.4 | V _{CCIO} – 0.4 | 8 | -8 |
| HSTL-18 Class II | _ | V _{REF} – 0.1 | V _{REF} + 0.1 | _ | V _{REF} - 0.2 | V _{REF} + 0.2 | 0.4 | V _{CCIO} – 0.4 | 16 | -16 |
| HSTL-15 Class I | _ | V _{REF} – 0.1 | V _{REF} + 0.1 | _ | V _{REF} - 0.2 | V _{REF} + 0.2 | 0.4 | V _{CCIO} – 0.4 | 8 | -8 |
| HSTL-15 Class II | _ | V _{REF} – 0.1 | V _{REF} + 0.1 | _ | V _{REF} - 0.2 | V _{REF} + 0.2 | 0.4 | V _{CCIO} – 0.4 | 16 | -16 |
| HSTL-12 Class I | -0.15 | V _{REF} – 0.08 | V _{REF} + 0.08 | V _{CCIO} + 0.15 | V _{REF} – 0.15 | V _{REF} + 0.15 | 0.25* V _{CCIO} | 0.75* V _{CCIO} | 8 | -8 |
| HSTL-12 Class II | -0.15 | V _{REF} – 0.08 | V _{REF} + 0.08 | V _{CCIO} + 0.15 | V _{REF} – 0.15 | V _{REF} + 0.15 | 0.25* V _{CCIO} | 0.75* V _{CCIO} | 16 | -16 |
| HSUL-12 | _ | V _{REF} – 0.13 | V _{REF} + 0.13 | _ | V _{REF} – 0.22 | V _{REF} + 0.22 | 0.1* V _{CCIO} | 0.9* V _{CCIO} | _ | |

Table 20. Differential SSTL I/O Standards for Stratix V Devices

| I/O Standard | | V _{CCIO} (V) | | V _{SWIN} | _{G(DC)} (V) | | V _{X(AC)} (V) | | V _{SWING(} | _{AC)} (V) |
|-------------------------|-------|-----------------------|-------|-------------------|-------------------------|------------------------------|------------------------|------------------------------|--|---|
| I/O Standard | Min | Тур | Max | Min | Max | Min | Тур | Max | Min | Max |
| SSTL-2 Class I, II | 2.375 | 2.5 | 2.625 | 0.3 | V _{CCIO} + 0.6 | V _{CCIO} /2 – 0.2 | _ | V _{CCIO} /2 + 0.2 | 0.62 | V _{CCIO} + 0.6 |
| SSTL-18 Class I, II | 1.71 | 1.8 | 1.89 | 0.25 | V _{CCIO} + 0.6 | V _{CCIO} /2 – 0.175 | _ | V _{CCIO} /2 + 0.175 | 0.5 | V _{CCIO} + 0.6 |
| SSTL-15 Class I, II | 1.425 | 1.5 | 1.575 | 0.2 | (1) | V _{CCIO} /2 – 0.15 | _ | V _{CCIO} /2 + 0.15 | 0.35 | _ |
| SSTL-135 Class I, II | 1.283 | 1.35 | 1.45 | 0.2 | (1) | V _{CCIO} /2 – 0.15 | V _{CCIO} /2 | V _{CCIO} /2 + 0.15 | 2(V _{IH(AC)} - V _{REF}) | 2(V _{IL(AC)} - V _{REF}) |
| SSTL-125 Class I, II | 1.19 | 1.25 | 1.31 | 0.18 | (1) | V _{CCIO} /2 – 0.15 | V _{CCIO} /2 | V _{CCIO} /2 + 0.15 | 2(V _{IH(AC)} - V _{REF}) | _ |
| SSTL-12 Class I, II | 1.14 | 1.2 | 1.26 | 0.18 | _ | V _{REF} -0.15 | V _{CCIO} /2 | V _{REF} + 0.15 | -0.30 | 0.30 |

Note to Table 20:

Table 21. Differential HSTL and HSUL I/O Standards for Stratix V Devices (Part 1 of 2)

| I/O | I/O V _{CC10} (V) | | | V _{DIF(} | _{DC)} (V) | V _{X(AC)} (V) | | | | V _{CM(DC)} (V |) | V _{DIF(AC)} (V) | |
|------------------------|---------------------------|-----|-------|-------------------|--------------------|------------------------|-----|------|------|------------------------|------|--------------------------|-----|
| Standard | Min | Тур | Max | Min | Max | Min | Тур | Max | Min | Тур | Max | Min | Max |
| HSTL-18 Class I, II | 1.71 | 1.8 | 1.89 | 0.2 | _ | 0.78 | _ | 1.12 | 0.78 | _ | 1.12 | 0.4 | _ |
| HSTL-15 Class I, II | 1.425 | 1.5 | 1.575 | 0.2 | | 0.68 | _ | 0.9 | 0.68 | | 0.9 | 0.4 | _ |

⁽¹⁾ The maximum value for $V_{SWING(DC)}$ is not defined. However, each single-ended signal needs to be within the respective single-ended limits $(V_{IH(DC)})$ and $V_{IL(DC)})$.

Page 16 Electrical Characteristics

Table 21. Differential HSTL and HSUL I/O Standards for Stratix V Devices (Part 2 of 2)

| I/O | V _{CCIO} (V) | | | V _{DIF(DC)} (V) | | | V _{X(AC)} (V) | | | V _{CM(DC)} (V |) | V _{DIF(AC)} (V) | |
|------------------------|-----------------------|-----|------|--------------------------|-------------------------|---------------------------------|---------------------------|---------------------------------|---------------------------|---------------------------|---------------------------|--------------------------|-----------------------------|
| Standard | Min | Тур | Max | Min | Max | Min | Тур | Max | Min | Тур | Max | Min | Max |
| HSTL-12 Class I, II | 1.14 | 1.2 | 1.26 | 0.16 | V _{CCIO} + 0.3 | _ | 0.5* V _{CCIO} | _ | 0.4* V _{CCIO} | 0.5* V _{CCIO} | 0.6* V _{CCIO} | 0.3 | V _{CCIO} + 0.48 |
| HSUL-12 | 1.14 | 1.2 | 1.3 | 0.26 | 0.26 | 0.5*V _{CCIO} - 0.12 | 0.5* V _{CCIO} | 0.5*V _{CCIO} + 0.12 | 0.4* V _{CCIO} | 0.5* V _{CCIO} | 0.6* V _{CCIO} | 0.44 | 0.44 |

Table 22. Differential I/O Standard Specifications for Stratix V Devices (7)

| I/O | Vc | _{CIO} (V) | (10) | | V _{ID} (mV) ⁽⁸⁾ | | | $V_{ICM(DC)}$ (V) | | V _o | _D (V) (| 6) | V _{OCM} (V) ⁽⁶⁾ | | | |
|------------------------------|---------------|--------------------|-----------|-----|-------------------------------------|-------------------|------|--------------------------------|-----------------------------|----------------|--------------------|-----|-------------------------------------|-------|-------|-------|
| Standard | Min | Тур | Max | Min | Condition | Max | Min | Condition | Max | Min | Тур | Max | Min | Тур | Max | |
| PCML | Trar | nsmitte | | | | | | of the high-s I/O pin speci | | | | | | | . For | |
| 2.5 V LVDS (1) 2.375 2.5 | 375 2.5 2.625 | | 2.5 2.625 | | 100 | V _{CM} = | _ | 0.05 | D _{MAX} ≤ 700 Mbps | 1.8 | 0.247 | _ | 0.6 | 1.125 | 1.25 | 1.375 |
| LVDS (1) | 2.373 | 2.3 | 2.023 | 100 | 1.25 V | | 1.05 | D _{MAX} > 700 Mbps | 1.55 | 0.247 | _ | 0.6 | 1.125 | 1.25 | 1.375 | |
| BLVDS (5) | 2.375 | 2.5 | 2.625 | 100 | _ | _ | _ | _ | _ | _ | _ | _ | _ | _ | _ | |
| RSDS (HIO) ⁽²⁾ | 2.375 | 2.5 | 2.625 | 100 | V _{CM} = 1.25 V | _ | 0.3 | _ | 1.4 | 0.1 | 0.2 | 0.6 | 0.5 | 1.2 | 1.4 | |
| Mini- LVDS (HIO) (3) | 2.375 | 2.5 | 2.625 | 200 | _ | 600 | 0.4 | _ | 1.325 | 0.25 | _ | 0.6 | 1 | 1.2 | 1.4 | |
| LVPECL (4 | _ | _ | _ | 300 | _ | _ | 0.6 | D _{MAX} ≤ 700 Mbps | 1.8 | _ | _ | _ | _ | _ | | |
|), (9) | _ | _ | _ | 300 | _ | _ | 1 | D _{MAX} > 700 Mbps | 1.6 | _ | _ | _ | _ | _ | _ | |

Notes to Table 22:

- (1) For optimized LVDS receiver performance, the receiver voltage input range must be between 1.0 V to 1.6 V for data rates above 700 Mbps, and 0 V to 1.85 V for data rates below 700 Mbps.
- (2) For optimized RSDS receiver performance, the receiver voltage input range must be between 0.25 V to 1.45 V.
- (3) For optimized Mini-LVDS receiver performance, the receiver voltage input range must be between 0.3 V to 1.425 V.
- (4) For optimized LVPECL receiver performance, the receiver voltage input range must be between 0.85 V to 1.75 V for data rate above 700 Mbps and 0.45 V to 1.95 V for data rate below 700 Mbps.
- (5) There are no fixed V_{ICM} , V_{OD} , and V_{OCM} specifications for BLVDS. They depend on the system topology.
- (6) RL range: $90 \le RL \le 110 \Omega$.
- (7) The 1.4-V and 1.5-V PCML transceiver I/O standard specifications are described in "Transceiver Performance Specifications" on page 18.
- (8) The minimum VID value is applicable over the entire common mode range, VCM.
- (9) LVPECL is only supported on dedicated clock input pins.
- (10) Differential inputs are powered by VCCPD which requires 2.5 $\rm V.$

Power Consumption

Altera offers two ways to estimate power consumption for a design—the Excel-based Early Power Estimator and the Quartus[®] II PowerPlay Power Analyzer feature.

Page 20 Switching Characteristics

Table 23. Transceiver Specifications for Stratix V GX and GS Devices $^{(1)}$ (Part 3 of 7)

| Symbol/ | Conditions | Trai | nsceive Grade | r Speed 1 | Trai | nsceive Grade | r Speed 2 | Trar | sceive Grade | er Speed e 3 | Unit |
|--|---|------|------------------|--------------|----------|------------------|--------------|---------|-----------------|--------------------------|------|
| Description | | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | |
| Reconfiguration clock (mgmt_clk_clk) frequency | _ | 100 | _ | 125 | 100 | _ | 125 | 100 | _ | 125 | MHz |
| Receiver | | | | | | | | | | | |
| Supported I/O Standards | _ | | | 1.4-V PCMI | L, 1.5-V | PCML, | 2.5-V PCM | L, LVPE | CL, and | d LVDS | |
| Data rate (Standard PCS) | _ | 600 | _ | 12200 | 600 | _ | 12200 | 600 | _ | 8500/ 10312.5 (24) | Mbps |
| Data rate (10G PCS) (9), (23) | _ | 600 | _ | 14100 | 600 | _ | 12500 | 600 | _ | 8500/ 10312.5 (24) | Mbps |
| Absolute V _{MAX} for a receiver pin ⁽⁵⁾ | _ | _ | _ | 1.2 | _ | _ | 1.2 | _ | _ | 1.2 | V |
| Absolute V _{MIN} for a receiver pin | _ | -0.4 | _ | _ | -0.4 | _ | _ | -0.4 | _ | _ | V |
| Maximum peak- to-peak differential input voltage V _{ID} (diff p- p) before device configuration (22) | _ | _ | _ | 1.6 | _ | _ | 1.6 | _ | _ | 1.6 | V |
| Maximum peak- | $V_{CCR_GXB} = 1.0 \text{ V}/1.05 \text{ V} $ $(V_{ICM} = 0.70 \text{ V})$ | _ | _ | 2.0 | _ | _ | 2.0 | _ | _ | 2.0 | V |
| differential input voltage V _{ID} (diff p- p) after device configuration (18), | $V_{CCR_GXB} = 0.90 \text{ V}$ $(V_{ICM} = 0.6 \text{ V})$ | | _ | 2.4 | _ | _ | 2.4 | _ | _ | 2.4 | V |
| (22) | $V_{CCR_GXB} = 0.85 \text{ V}$ $(V_{ICM} = 0.6 \text{ V})$ | _ | _ | 2.4 | _ | _ | 2.4 | _ | _ | 2.4 | V |
| Minimum differential eye opening at receiver serial input pins (6), (22), (27) | _ | 85 | _ | _ | 85 | _ | _ | 85 | _ | _ | mV |

Table 26 shows the approximate maximum data rate using the 10G PCS.

Table 26. Stratix V 10G PCS Approximate Maximum Data Rate (1)

| Mode ⁽²⁾ | Transceiver | PMA Width | 64 | 40 | 40 | 40 | 32 | 32 | | | |
|---------------------|-------------|--|--------------|-------|-------|------|----------|-------|--|--|--|
| Widue (2) | Speed Grade | PCS Width | 64 | 66/67 | 50 | 40 | 64/66/67 | 32 | | | |
| | 1 | C1, C2, C2L, I2, I2L core speed grade | 14.1 | 14.1 | 10.69 | 14.1 | 13.6 | 13.6 | | | |
| | 2 | C1, C2, C2L, I2, I2L core speed grade | 12.5 | 12.5 | 10.69 | 12.5 | 12.5 | 12.5 | | | |
| | 2 | C3, I3, I3L core speed grade | 12.5 | 12.5 | 10.69 | 12.5 | 10.88 | 10.88 | | | |
| FIFO or Register | | C1, C2, C2L, I2, I2L core speed grade | | | | | | | | | |
| | 2 | C3, I3, I3L core speed grade | | | 8.5 | Gbps | | | | | |
| | 3 | C4, I4 core speed grade | le | | | | | | | | |
| | | I3YY core speed grade | 10.3125 Gbps | | | | | | | | |

Notes to Table 26:

⁽¹⁾ The maximum data rate is in Gbps.

⁽²⁾ The Phase Compensation FIFO can be configured in FIFO mode or register mode. In the FIFO mode, the pointers are not fixed, and the latency can vary. In the register mode the pointers are fixed for low latency.

Table 28. Transceiver Specifications for Stratix V GT Devices (Part 4 of 5) $^{(1)}$

| Symbol/ | Conditions | | Transceive peed Grade | | | Transceive Deed Grade | | Unit | | |
|--|--|--------|--------------------------|--------------------------------|--------|--------------------------|--------------------------------|------|--|--|
| Description | | Min | Тур | Max | Min | Тур | Max | | | |
| Data rate | GT channels | 19,600 | _ | 28,050 | 19,600 | _ | 25,780 | Mbps | | |
| Differential on-chip | GT channels | _ | 100 | _ | | 100 | <u> </u> | Ω | | |
| termination resistors | GX channels | | | • | (8) | | <u>'</u> | | | |
| \/ | GT channels | _ | 500 | _ | _ | 500 | _ | mV | | |
| V _{OCM} (AC coupled) | GX channels | | | • | (8) | | <u>'</u> | | | |
| Diag/Fall time | GT channels | _ | 15 | _ | _ | 15 | _ | ps | | |
| Rise/Fall time | GX channels | | <u>I</u> | | (8) | | | | | |
| Intra-differential pair skew | GX channels | | | | (8) | | | | | |
| Intra-transceiver block transmitter channel-to- channel skew | GX channels | | (8) | | | | | | | |
| Inter-transceiver block transmitter channel-to- channel skew | GX channels | | | | (8) | | | | | |
| CMU PLL | | | | | | | | | | |
| Supported Data Range | _ | 600 | _ | 12500 | 600 | _ | 8500 | Mbps | | |
| t _{pll_powerdown} (13) | _ | 1 | _ | _ | 1 | _ | _ | μs | | |
| t _{pll_lock} (14) | _ | _ | _ | 10 | _ | _ | 10 | μs | | |
| ATX PLL | | | | | | | | | | |
| | VCO post- divider L=2 | 8000 | _ | 12500 | 8000 | _ | 8500 | Mbps | | |
| | L=4 | 4000 | _ | 6600 | 4000 | _ | 6600 | Mbps | | |
| Supported Data Rate | L=8 | 2000 | _ | 3300 | 2000 | _ | 3300 | Mbps | | |
| Range for GX Channels | L=8, Local/Central Clock Divider =2 | 1000 | _ | 1762.5 | 1000 | _ | 1762.5 | Mbps | | |
| Supported Data Rate Range for GT Channels | VCO post- divider L=2 | 9800 | _ | 14025 | 9800 | _ | 12890 | Mbps | | |
| t _{pll_powerdown} (13) | _ | 1 | _ | _ | 1 | _ | _ | μs | | |
| t _{pll_lock} (14) | _ | _ | _ | 10 | _ | _ | 10 | μs | | |
| fPLL | | | • | | | | | | | |
| Supported Data Range | _ | 600 | _ | 3250/ 3.125 ⁽²³⁾ | 600 | _ | 3250/ 3.125 ⁽²³⁾ | Mbps | | |
| t _{pll_powerdown} (13) | _ | 1 | _ | _ | 1 | _ | _ | μs | | |

Page 36 Switching Characteristics

Figure 4 shows the differential transmitter output waveform.

Figure 4. Differential Transmitter/Receiver Output/Input Waveform

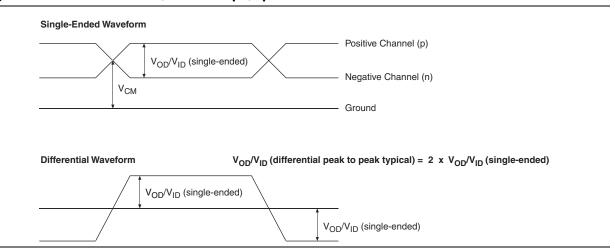


Figure 5 shows the Stratix V AC gain curves for GT channels.

Figure 5. AC Gain Curves for GT Channels

Page 38 Switching Characteristics

- XFI
- ASI
- HiGig/HiGig+
- HiGig2/HiGig2+
- Serial Data Converter (SDC)
- GPON
- SDI
- SONET
- Fibre Channel (FC)
- PCIe
- QPI
- SFF-8431

Download the Stratix V Characterization Report Tool to view the characterization report summary for these protocols.

Core Performance Specifications

This section describes the clock tree, phase-locked loop (PLL), digital signal processing (DSP), memory blocks, configuration, and JTAG specifications.

Clock Tree Specifications

Table 30 lists the clock tree specifications for Stratix V devices.

Table 30. Clock Tree Performance for Stratix V Devices (1)

| | Performance | | | | | | | |
|------------------------------|--------------------------|--------------------------|--------|------|--|--|--|--|
| Symbol | C1, C2, C2L, I2, and I2L | C3, I3, I3L, and I3YY | C4, I4 | Unit | | | | |
| Global and Regional Clock | 717 | 650 | 580 | MHz | | | | |
| Periphery Clock | 550 | 500 | 500 | MHz | | | | |

Note to Table 30:

(1) The Stratix V ES devices are limited to 600 MHz core clock tree performance.

Page 40 Switching Characteristics

Table 31. PLL Specifications for Stratix V Devices (Part 2 of 3)

| Symbol | Parameter | Min | Тур | Max | Unit |
|--|---|------|---------|--|-----------|
| → (3) (4) | Input clock cycle-to-cycle jitter (f _{REF} ≥ 100 MHz) | _ | _ | 0.15 | UI (p-p) |
| t _{INCCJ} (3), (4) | Input clock cycle-to-cycle jitter (f _{REF} < 100 MHz) | -750 | | +750 | ps (p-p) |
| + (5) | Period Jitter for dedicated clock output ($f_{OUT} \ge 100 \text{ MHz}$) | _ | _ | 175 ⁽¹⁾ | ps (p-p) |
| t _{OUTPJ_DC} (5) | Period Jitter for dedicated clock output (f _{OUT} < 100 MHz) | _ | _ | 17.5 ⁽¹⁾ | mUI (p-p) |
| + (5) | Period Jitter for dedicated clock output in fractional PLL ($f_{OUT} \ge 100 \text{ MHz}$) | _ | _ | 250 ⁽¹¹⁾ , 175 ⁽¹²⁾ | ps (p-p) |
| t _{FOUTPJ_DC} (5) | Period Jitter for dedicated clock output in fractional PLL (f _{OUT} < 100 MHz) | _ | _ | 25 ⁽¹¹⁾ , 17.5 ⁽¹²⁾ | mUI (p-p) |
| + (5) | Cycle-to-Cycle Jitter for a dedicated clock output $(f_{OUT} \ge 100 \text{ MHz})$ | _ | _ | 175 | ps (p-p) |
| t _{outccj_dc} (5) | Cycle-to-Cycle Jitter for a dedicated clock output (f _{OUT} < 100 MHz) | _ | _ | 17.5 | mUI (p-p) |
| + (5) | Cycle-to-cycle Jitter for a dedicated clock output in fractional PLL ($f_{OUT} \ge 100 \text{ MHz}$) | _ | _ | 250 ⁽¹¹⁾ , 175 ⁽¹²⁾ | ps (p-p) |
| t _{FOUTCCJ_DC} ⁽⁵⁾ | Cycle-to-cycle Jitter for a dedicated clock output in fractional PLL (f _{OUT} < 100 MHz)+ | _ | _ | 25 ⁽¹¹⁾ , 17.5 ⁽¹²⁾ | mUI (p-p) |
| t _{OUTPJ_IO} (5), | Period Jitter for a clock output on a regular I/O in integer PLL ($f_{OUT} \ge 100 \text{ MHz}$) | _ | _ | 600 | ps (p-p) |
| (8) | Period Jitter for a clock output on a regular I/O (f _{OUT} < 100 MHz) | _ | _ | 60 | mUI (p-p) |
| t _{FOUTPJ 10} (5), | Period Jitter for a clock output on a regular I/O in fractional PLL ($f_{OUT} \ge 100 \text{ MHz}$) | _ | _ | 600 (10) | ps (p-p) |
| (8), (11) | Period Jitter for a clock output on a regular I/O in fractional PLL (f_{OUT} < 100 MHz) | _ | _ | 60 (10) | mUI (p-p) |
| t _{outccj_10} (5), | Cycle-to-cycle Jitter for a clock output on a regular I/O in integer PLL ($f_{OUT} \ge 100$ MHz) | _ | _ | 600 | ps (p-p) |
| (8) | Cycle-to-cycle Jitter for a clock output on a regular I/O in integer PLL (f_{OUT} < 100 MHz) | _ | _ | 60 (10) | mUI (p-p) |
| t _{FOUTCCJ_IO} | Cycle-to-cycle Jitter for a clock output on a regular I/O in fractional PLL ($f_{OUT} \ge 100$ MHz) | _ | _ | 600 (10) | ps (p-p) |
| (8), (11) | Cycle-to-cycle Jitter for a clock output on a regular I/O in fractional PLL (f_{OUT} < 100 MHz) | _ | _ | 60 | mUI (p-p) |
| t _{CASC_OUTPJ_DC} | Period Jitter for a dedicated clock output in cascaded PLLs ($f_{OUT} \ge 100 \text{ MHz}$) | _ | _ | 175 | ps (p-p) |
| (5), (6) | Period Jitter for a dedicated clock output in cascaded PLLs (f _{OUT} < 100 MHz) | _ | _ | 17.5 | mUI (p-p) |
| f _{DRIFT} | Frequency drift after PFDENA is disabled for a duration of 100 μs | _ | _ | ±10 | % |
| dK _{BIT} | Bit number of Delta Sigma Modulator (DSM) | 8 | 24 | 32 | Bits |
| k _{VALUE} | Numerator of Fraction | 128 | 8388608 | 2147483648 | _ |

Page 44 Switching Characteristics

Periphery Performance

This section describes periphery performance, including high-speed I/O and external memory interface.

I/O performance supports several system interfaces, such as the **LVDS** high-speed I/O interface, external memory interface, and the **PCI/PCI-X** bus interface. General-purpose I/O standards such as 3.3-, 2.5-, 1.8-, and 1.5-**LVTTL/LVCMOS** are capable of a typical 167 MHz and 1.2-**LVCMOS** at 100 MHz interfacing frequency with a 10 pF load.



The actual achievable frequency depends on design- and system-specific factors. Ensure proper timing closure in your design and perform HSPICE/IBIS simulations based on your specific design and system setup to determine the maximum achievable frequency in your system.

High-Speed I/O Specification

Table 36 lists high-speed I/O timing for Stratix V devices.

Table 36. High-Speed I/O Specifications for Stratix V Devices (1), (2) (Part 1 of 4)

| _ | | | | | | | | | | | | | | |
|--|---------------------------------------|-----|-----|-----|-----|--------|--------|-------------------|-----|------------|-----|-----|------------|------|
| Cumbal | Conditions | C1 | | | C2, | C2L, I | 2, I2L | C3, I3, I3L, I3YY | | C4,I4 | | | Unit | |
| Symbol | Conuntions | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| f _{HSCLK_in} (input clock frequency) True Differential I/O Standards | Clock boost factor W = 1 to 40 (4) | 5 | | 800 | 5 | _ | 800 | 5 | | 625 | 5 | | 525 | MHz |
| f _{HSCLK_in} (input clock frequency) Single Ended I/O Standards (3) | Clock boost factor W = 1 to 40 (4) | 5 | | 800 | 5 | _ | 800 | 5 | | 625 | 5 | | 525 | MHz |
| f _{HSCLK_in} (input clock frequency) Single Ended I/O Standards | Clock boost factor W = 1 to 40 (4) | 5 | | 520 | 5 | _ | 520 | 5 | | 420 | 5 | | 420 | MHz |
| f _{HSCLK_OUT} (output clock frequency) | _ | 5 | | 800 | 5 | _ | 800 | 5 | | 625 (5) | 5 | | 525 (5) | MHz |

Page 46 Switching Characteristics

Table 36. High-Speed I/O Specifications for Stratix V Devices (1), (2) (Part 3 of 4)

| | | | C1 | | C2, | C2L, I | 2, I2L | C3, | 13, I3L | ., I3YY | C4,14 | | | |
|---------------------------------------|---|-----|-----|------|-----|--------|--------|-----|---------|---------|-------|-----|------|------|
| Symbol | Conditions | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| t _{DUTY} | Transmitter output clock duty cycle for both True and Emulated Differential I/O Standards | 45 | 50 | 55 | 45 | 50 | 55 | 45 | 50 | 55 | 45 | 50 | 55 | % |
| | True Differential I/O Standards | _ | _ | 160 | _ | _ | 160 | _ | _ | 200 | _ | _ | 200 | ps |
| t _{RISE} & t _{FALL} | Emulated Differential I/O Standards with three external output resistor networks | _ | | 250 | _ | _ | 250 | _ | | 250 | _ | | 300 | ps |
| | True Differential I/O Standards | _ | _ | 150 | _ | | 150 | | _ | 150 | | _ | 150 | ps |
| TCCS | Emulated Differential I/O Standards | _ | _ | 300 | _ | _ | 300 | _ | | 300 | _ | | 300 | ps |
| Receiver | | | | | | | | | | | | | | |
| | SERDES factor J = 3 to 10 (11), (12), (13), (14), (15), (16) | 150 | _ | 1434 | 150 | _ | 1434 | 150 | _ | 1250 | 150 | _ | 1050 | Mbps |
| True Differential I/O Standards | SERDES factor J ≥ 4 LVDS RX with DPA (12), (14), (15), (16) | 150 | _ | 1600 | 150 | _ | 1600 | 150 | _ | 1600 | 150 | _ | 1250 | Mbps |
| - f _{HSDRDPA} (data rate) | SERDES factor J = 2, uses DDR Registers | (6) | _ | (7) | (6) | _ | (7) | (6) | | (7) | (6) | | (7) | Mbps |
| | SERDES factor J = 1, uses SDR Register | (6) | _ | (7) | (6) | _ | (7) | (6) | | (7) | (6) | _ | (7) | Mbps |

Table 36. High-Speed I/O Specifications for Stratix V Devices (1), (2) (Part 4 of 4)

| Cumbal | Conditions | | C1 | | C2, | C2L, I | 2, I2L | C3, | I3, I3I | ., I3YY | C4,I4 | | | Unit |
|-------------------------------|--|-----|-----|-----------|-----|--------|-----------|-----|---------|-----------|-------|-----|-----------|----------|
| Symbol | Conuntions | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Ullit |
| | SERDES factor J = 3 to 10 | (6) | _ | (8) | (6) | | (8) | (6) | | (8) | (6) | _ | (8) | Mbps |
| f _{HSDR} (data rate) | SERDES factor J = 2, uses DDR Registers | (6) | | (7) | (6) | | (7) | (6) | | (7) | (6) | | (7) | Mbps |
| | SERDES factor J = 1, uses SDR Register | (6) | _ | (7) | (6) | _ | (7) | (6) | _ | (7) | (6) | _ | (7) | Mbps |
| DPA Mode | | | | | | | | | | | | | | |
| DPA run length | _ | | _ | 1000 0 | | | 1000 0 | _ | | 1000 0 | _ | _ | 1000 0 | UI |
| Soft CDR mode | • | | | | | | | | | | | | | |
| Soft-CDR PPM tolerance | _ | _ | _ | 300 | _ | _ | 300 | _ | _ | 300 | _ | _ | 300 | ± PPM |
| Non DPA Mode | Non DPA Mode | | | | | | | | | | | | | |
| Sampling Window | _ | _ | _ | 300 | _ | | 300 | _ | | 300 | _ | _ | 300 | ps |

Notes to Table 36:

- (1) When J = 3 to 10, use the serializer/deserializer (SERDES) block.
- (2) When J = 1 or 2, bypass the SERDES block.
- (3) This only applies to DPA and soft-CDR modes.
- (4) Clock Boost Factor (W) is the ratio between the input data rate to the input clock rate.
- (5) This is achieved by using the **LVDS** clock network.
- (6) The minimum specification depends on the clock source (for example, the PLL and clock pin) and the clock routing resource (global, regional, or local) that you use. The I/O differential buffer and input register do not have a minimum toggle rate.
- (7) The maximum ideal frequency is the SERDES factor (J) x the PLL maximum output frequency (fOUT) provided you can close the design timing and the signal integrity simulation is clean.
- (8) You can estimate the achievable maximum data rate for non-DPA mode by performing link timing closure analysis. You must consider the board skew margin, transmitter delay margin, and receiver sampling margin to determine the maximum data rate supported.
- (9) If the receiver with DPA enabled and transmitter are using shared PLLs, the minimum data rate is 150 Mbps.
- (10) You must calculate the leftover timing margin in the receiver by performing link timing closure analysis. You must consider the board skew margin, transmitter channel-to-channel skew, and receiver sampling margin to determine leftover timing margin.
- (11) The F_{MAX} specification is based on the fast clock used for serial data. The interface F_{MAX} is also dependent on the parallel clock domain which is design-dependent and requires timing analysis.
- (12) Stratix V RX LVDS will need DPA. For Stratix V TX LVDS, the receiver side component must have DPA.
- (13) Stratix V LVDS serialization and de-serialization factor needs to be x4 and above.
- (14) Requires package skew compensation with PCB trace length.
- (15) Do not mix single-ended I/O buffer within LVDS I/O bank.
- (16) Chip-to-chip communication only with a maximum load of 5 pF.
- (17) When using True LVDS RX channels for emulated LVDS TX channel, only serialization factors 1 and 2 are supported.

Page 48 Switching Characteristics

Figure 7 shows the dynamic phase alignment (DPA) lock time specifications with the DPA PLL calibration option enabled.

Figure 7. DPA Lock Time Specification with DPA PLL Calibration Enabled

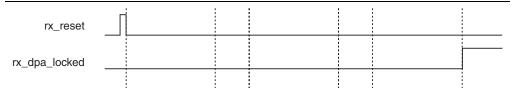


Table 37 lists the DPA lock time specifications for Stratix V devices.

Table 37. DPA Lock Time Specifications for Stratix V GX Devices Only (1), (2), (3)

| Standard | Training Pattern | Number of Data Transitions in One Repetition of the Training Pattern | Number of Repetitions per 256 Data Transitions ⁽⁴⁾ | Maximum | |
|--------------------|---------------------|---|---|----------------------|--|
| SPI-4 | 0000000001111111111 | 2 | 128 | 640 data transitions | |
| Parallel Rapid I/O | 00001111 | 2 | 128 | 640 data transitions | |
| Faranei napiu 1/0 | 10010000 | 4 | 64 | 640 data transitions | |
| Miscellaneous | 10101010 | 8 | 32 | 640 data transitions | |
| IVIISCEIIAIIEOUS | 01010101 | 8 | 32 | 640 data transitions | |

Notes to Table 37:

- (1) The DPA lock time is for one channel.
- (2) One data transition is defined as a 0-to-1 or 1-to-0 transition.
- (3) The DPA lock time stated in this table applies to both commercial and industrial grade.
- (4) This is the number of repetitions for the stated training pattern to achieve the 256 data transitions.

Figure 8 shows the **LVDS** soft-clock data recovery (CDR)/DPA sinusoidal jitter tolerance specification for a data rate \geq 1.25 Gbps. Table 38 lists the **LVDS** soft-CDR/DPA sinusoidal jitter tolerance specification for a data rate \geq 1.25 Gbps.

Figure 8. LVDS Soft-CDR/DPA Sinusoidal Jitter Tolerance Specification for a Data Rate \geq 1.25 Gbps

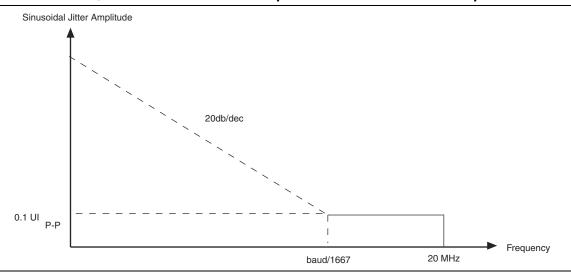
LVDS Soft-CDR/DPA Sinusoidal Jitter Tolerance Specification

Table 38. LVDS Soft-CDR/DPA Sinusoidal Jitter Mask Values for a Data Rate \geq 1.25 Gbps

| Jitter Fr | equency (Hz) | Sinusoidal Jitter (UI) |
|-----------|--------------|------------------------|
| F1 | 10,000 | 25.000 |
| F2 | 17,565 | 25.000 |
| F3 | 1,493,000 | 0.350 |
| F4 | 50,000,000 | 0.350 |

Figure 9 shows the **LVDS** soft-CDR/DPA sinusoidal jitter tolerance specification for a data rate < 1.25 Gbps.

Figure 9. LVDS Soft-CDR/DPA Sinusoidal Jitter Tolerance Specification for a Data Rate < 1.25 Gbps



DLL Range, DQS Logic Block, and Memory Output Clock Jitter Specifications

Table 39 lists the DLL range specification for Stratix V devices. The DLL is always in 8-tap mode in Stratix V devices.

Table 39. DLL Range Specifications for Stratix V Devices (1)

| C1 | C2, C2L, I2, I2L | C3, I3, I3L, I3YY | C4,I4 | Unit |
|---------|------------------|-------------------|---------|------|
| 300-933 | 300-933 | 300-890 | 300-890 | MHz |

Note to Table 39:

(1) Stratix V devices support memory interface frequencies lower than 300 MHz, although the reference clock that feeds the DLL must be at least 300 MHz. To support interfaces below 300 MHz, multiply the reference clock feeding the DLL to ensure the frequency is within the supported range of the DLL.

Table 40 lists the DQS phase offset delay per stage for Stratix V devices.

Table 40. DQS Phase Offset Delay Per Setting for Stratix V Devices (1), (2) (Part 1 of 2)

| Speed Grade | Min | Max | Unit |
|------------------|-----|-----|------|
| C1 | 8 | 14 | ps |
| C2, C2L, I2, I2L | 8 | 14 | ps |
| C3,I3, I3L, I3YY | 8 | 15 | ps |

Page 50 Switching Characteristics

Table 40. DQS Phase Offset Delay Per Setting for Stratix V Devices (1), (2) (Part 2 of 2)

| Speed Grade | Min | Max | Unit |
|-------------|-----|-----|------|
| C4,I4 | 8 | 16 | ps |

Notes to Table 40:

- (1) The typical value equals the average of the minimum and maximum values.
- (2) The delay settings are linear with a cumulative delay variation of 40 ps for all speed grades. For example, when using a -2 speed grade and applying a 10-phase offset setting to a 90° phase shift at 400 MHz, the expected average cumulative delay is [625 ps + (10 × 10 ps) ± 20 ps] = 725 ps ± 20 ps.

Table 41 lists the DQS phase shift error for Stratix V devices.

Table 41. DQS Phase Shift Error Specification for DLL-Delayed Clock (t_{DQS_PSERR}) for Stratix V Devices (1)

| Number of DQS Delay Buffers | C1 | C2, C2L, I2, I2L | C3, I3, I3L, I3YY | C4,I4 | Unit |
|--------------------------------|-----|------------------|-------------------|-------|------|
| 1 | 28 | 28 | 30 | 32 | ps |
| 2 | 56 | 56 | 60 | 64 | ps |
| 3 | 84 | 84 | 90 | 96 | ps |
| 4 | 112 | 112 | 120 | 128 | ps |

Notes to Table 41:

Table 42 lists the memory output clock jitter specifications for Stratix V devices.

Table 42. Memory Output Clock Jitter Specification for Stratix V Devices (1), (Part 1 of 2) (2), (3)

| Clock | Parameter | Symbol | C1 | | C2, C2L, I2, I2L | | C3, I3, I3L, I3YY | | C4,I4 | | Unit |
|----------|------------------------------|------------------------|-----------------|-----|------------------|-----|----------------------|------|-------|------|------|
| Network | | | Min | Max | Min | Max | Min | Max | Min | Max | |
| | Clock period jitter | t _{JIT(per)} | -50 | 50 | -50 | 50 | -55 | 55 | -55 | 55 | ps |
| Regional | Cycle-to-cycle period jitter | t _{JIT(cc)} | -100 | 100 | -100 | 100 | -110 | 110 | -110 | 110 | ps |
| | Duty cycle jitter | $t_{JIT(duty)}$ | -50 | 50 | -50 | 50 | -82.5 | 82.5 | -82.5 | 82.5 | ps |
| | Clock period jitter | t _{JIT(per)} | -75 | 75 | -75 | 75 | -82.5 | 82.5 | -82.5 | 82.5 | ps |
| Global | Cycle-to-cycle period jitter | t _{JIT(cc)} | -150 | 150 | -150 | 150 | -165 | 165 | -165 | 165 | ps |
| | Duty cycle jitter | t _{JIT(duty)} | - 75 | 75 | - 75 | 75 | -90 | 90 | -90 | 90 | ps |

⁽¹⁾ This error specification is the absolute maximum and minimum error. For example, skew on three DQS delay buffers in a −2 speed grade is ±78 ps or ±39 ps.

Table 42. Memory Output Clock Jitter Specification for Stratix V Devices (1), (Part 2 of 2) (2), (3)

| Clock | Parameter | Symbol | C 1 | | C2, C2L, I2, I2L | | C3, I3, I3L, I3YY | | C4,I4 | | Unit |
|--------------|------------------------------|-----------------------|------------|------|------------------|------|----------------------|-----|-------|-----|------|
| Network | | | Min | Max | Min | Max | Min | Max | Min | Max | |
| | Clock period jitter | $t_{\text{JIT(per)}}$ | -25 | 25 | -25 | 25 | -30 | 30 | -35 | 35 | ps |
| PHY Clock | Cycle-to-cycle period jitter | t _{JIT(cc)} | -50 | 50 | - 50 | 50 | -60 | 60 | -70 | 70 | ps |
| | Duty cycle jitter | $t_{JIT(duty)}$ | -37.5 | 37.5 | -37.5 | 37.5 | -45 | 45 | -56 | 56 | ps |

Notes to Table 42:

- (1) The clock jitter specification applies to the memory output clock pins generated using differential signal-splitter and DDIO circuits clocked by a PLL output routed on a PHY, regional, or global clock network as specified. Altera recommends using PHY clock networks whenever possible.
- (2) The clock jitter specification applies to the memory output clock pins clocked by an integer PLL.
- (3) The memory output clock jitter is applicable when an input jitter of 30 ps peak-to-peak is applied with bit error rate (BER) -12, equivalent to 14 sigma.

OCT Calibration Block Specifications

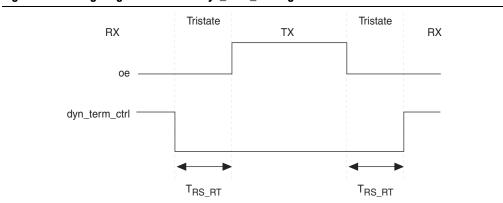
Table 43 lists the OCT calibration block specifications for Stratix V devices.

Table 43. OCT Calibration Block Specifications for Stratix V Devices

| Symbol | Description | Min | Тур | Max | Unit |
|-----------------------|--|-----|------|-----|--------|
| OCTUSRCLK | Clock required by the OCT calibration blocks | _ | _ | 20 | MHz |
| T _{OCTCAL} | Number of OCTUSRCLK clock cycles required for OCT $\ensuremath{R}_{\ensuremath{S}}/\ensuremath{R}_{\ensuremath{T}}$ calibration | | 1000 | _ | Cycles |
| T _{OCTSHIFT} | Number of OCTUSRCLK clock cycles required for the OCT code to shift out | | 32 | _ | Cycles |
| T _{RS_RT} | Time required between the $\mathtt{dyn_term_ctrl}$ and oe signal transitions in a bidirectional I/O buffer to dynamically switch between OCT R_S and R_T (Figure 10) | _ | 2.5 | _ | ns |

Figure 10 shows the timing diagram for the oe and dyn term ctrl signals.

Figure 10. Timing Diagram for oe and dyn_term_ctrl Signals



Page 54 Configuration Specification

Table 47. Uncompressed .rbf Sizes for Stratix V Devices

| Family | Device | Package | Configuration .rbf Size (bits) | IOCSR .rbf Size (bits) (4), (5) |
|-----------------|--------|---------|--------------------------------|---------------------------------|
| Stratix V E (1) | 5SEE9 | _ | 342,742,976 | 700,888 |
| Stratix V L () | 5SEEB | _ | 342,742,976 | 700,888 |

Notes to Table 47:

- (1) Stratix V E devices do not have PCI Express® (PCIe®) hard IP. Stratix V E devices do not support the CvP configuration scheme.
- (2) 36-transceiver devices.
- (3) 24-transceiver devices.
- (4) File size for the periphery image.
- (5) The IOCSR .rbf size is specifically for the CvP feature.

Use the data in Table 47 to estimate the file size before design compilation. Different configuration file formats, such as a hexadecimal (.hex) or tabular text file (.ttf) format, have different file sizes. For the different types of configuration file and file sizes, refer to the Quartus II software. However, for a specific version of the Quartus II software, any design targeted for the same device has the same uncompressed configuration file size. If you are using compression, the file size can vary after each compilation because the compression ratio depends on your design.

For more information about setting device configuration options, refer to *Configuration, Design Security, and Remote System Upgrades in Stratix V Devices.* For creating configuration files, refer to the *Quartus II Help*.

Table 48 lists the minimum configuration time estimates for Stratix V devices.

Table 48. Minimum Configuration Time Estimation for Stratix V Devices

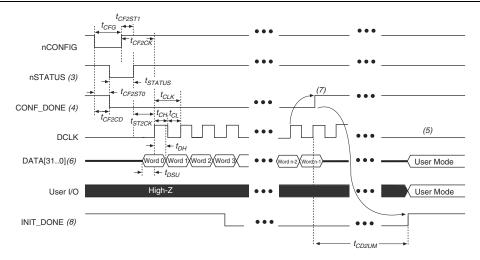
| | Member Code | | Active Serial (1) |) | Fast Passive Parallel (2) | | | |
|---------|----------------|-------|-------------------|------------------------|---------------------------|------------|------------------------|--|
| Variant | | Width | DCLK (MHz) | Min Config Time (s) | Width | DCLK (MHz) | Min Config Time (s) | |
| | A3 | 4 | 100 | 0.534 | 32 | 100 | 0.067 | |
| | AS | 4 | 100 | 0.344 | 32 | 100 | 0.043 | |
| | A4 | 4 | 100 | 0.534 | 32 | 100 | 0.067 | |
| | A5 | 4 | 100 | 0.675 | 32 | 100 | 0.084 | |
| | A7 | 4 | 100 | 0.675 | 32 | 100 | 0.084 | |
| GX | A9 | 4 | 100 | 0.857 | 32 | 100 | 0.107 | |
| | AB | 4 | 100 | 0.857 | 32 | 100 | 0.107 | |
| | B5 | 4 | 100 | 0.676 | 32 | 100 | 0.085 | |
| | B6 | 4 | 100 | 0.676 | 32 | 100 | 0.085 | |
| | В9 | 4 | 100 | 0.857 | 32 | 100 | 0.107 | |
| | BB | 4 | 100 | 0.857 | 32 | 100 | 0.107 | |
| GT | C5 | 4 | 100 | 0.675 | 32 | 100 | 0.084 | |
| G1 | C7 | 4 | 100 | 0.675 | 32 | 100 | 0.084 | |

Configuration Specification Page 57

FPP Configuration Timing when DCLK-to-DATA [] = 1

Figure 12 shows the timing waveform for FPP configuration when using a MAX II or MAX V device as an external host. This waveform shows timing when the DCLK-to-DATA[] ratio is 1.

Figure 12. FPP Configuration Timing Waveform When the DCLK-to-DATA[] Ratio is 1 (1), (2)



Notes to Figure 12:

- (1) Use this timing waveform when the DCLK-to-DATA[] ratio is 1.
- (2) The beginning of this waveform shows the device in user mode. In user mode, nCONFIG, nSTATUS, and CONF_DONE are at logic-high levels. When nCONFIG is pulled low, a reconfiguration cycle begins.
- (3) After power-up, the Stratix V device holds nSTATUS low for the time of the POR delay.
- (4) After power-up, before and during configuration, CONF DONE is low.
- (5) Do not leave DCLK floating after configuration. DCLK is ignored after configuration is complete. It can toggle high or low if required.
- (6) For FPP ×16, use DATA [15..0]. For FPP ×8, use DATA [7..0]. DATA [31..0] are available as a user I/O pin after configuration. The state of this pin depends on the dual-purpose pin settings.
- (7) To ensure a successful configuration, send the entire configuration data to the Stratix V device. CONF_DONE is released high when the Stratix V device receives all the configuration data successfully. After CONF_DONE goes high, send two additional falling edges on DCLK to begin initialization and enter user mode.
- (8) After the option bit to enable the <code>INIT_DONE</code> pin is configured into the device, the <code>INIT_DONE</code> goes low.

Document Revision History Page 71

Table 61. Document Revision History (Part 3 of 3)

| Date | Version | Changes |
|---------------|---------|---|
| | | ■ Updated Table 2, Table 6, Table 7, Table 20, Table 23, Table 27, Table 47, Table 60 |
| May 2013 | 2.7 | ■ Added Table 24, Table 48 |
| | | ■ Updated Figure 9, Figure 10, Figure 11, Figure 12 |
| February 2013 | 2.6 | ■ Updated Table 7, Table 9, Table 20, Table 23, Table 27, Table 30, Table 31, Table 35, Table 46 |
| , | | ■ Updated "Maximum Allowed Overshoot and Undershoot Voltage" |
| | | ■ Updated Table 3, Table 6, Table 7, Table 8, Table 23, Table 24, Table 25, Table 27, Table 30, Table 32, Table 35 |
| | | ■ Added Table 33 |
| | | ■ Added "Fast Passive Parallel Configuration Timing" |
| D | 0.5 | ■ Added "Active Serial Configuration Timing" |
| December 2012 | 2.5 | ■ Added "Passive Serial Configuration Timing" |
| | | ■ Added "Remote System Upgrades" |
| | | ■ Added "User Watchdog Internal Circuitry Timing Specification" |
| | | ■ Added "Initialization" |
| | | ■ Added "Raw Binary File Size" |
| | | ■ Added Figure 1, Figure 2, and Figure 3. |
| June 2012 | 2.4 | ■ Updated Table 1, Table 2, Table 3, Table 6, Table 11, Table 22, Table 23, Table 27, Table 29, Table 30, Table 31, Table 32, Table 35, Table 38, Table 39, Table 40, Table 41, Table 43, Table 56, and Table 59. |
| | | Various edits throughout to fix bugs. |
| | | ■ Changed title of document to Stratix V Device Datasheet. |
| | | ■ Removed document from the Stratix V handbook and made it a separate document. |
| February 2012 | 2.3 | ■ Updated Table 1–22, Table 1–29, Table 1–31, and Table 1–31. |
| December 2011 | 2.2 | ■ Added Table 2–31. |
| December 2011 | 2.2 | ■ Updated Table 2–28 and Table 2–34. |
| Nevember 0011 | 0.1 | ■ Added Table 2–2 and Table 2–21 and updated Table 2–5 with information about Stratix V GT devices. |
| November 2011 | 2.1 | ■ Updated Table 2–11, Table 2–13, Table 2–20, and Table 2–25. |
| | | ■ Various edits throughout to fix SPRs. |
| | | ■ Updated Table 2–4, Table 2–18, Table 2–19, Table 2–21, Table 2–22, Table 2–23, and Table 2–24. |
| May 2011 | 2.0 | ■ Updated the "DQ Logic Block and Memory Output Clock Jitter Specifications" title. |
| | | ■ Chapter moved to Volume 1. |
| | | ■ Minor text edits. |
| | | ■ Updated Table 1–2, Table 1–4, Table 1–19, and Table 1–23. |
| December 2010 | 1.1 | Converted chapter to the new template. |
| | | ■ Minor text edits. |
| July 2010 | 1.0 | Initial release. |